

Technical Data Green Products

Data Sheet N1159, Rev. -

# Power Surface Mount Schottky Rectifier (45V, 120Amp)

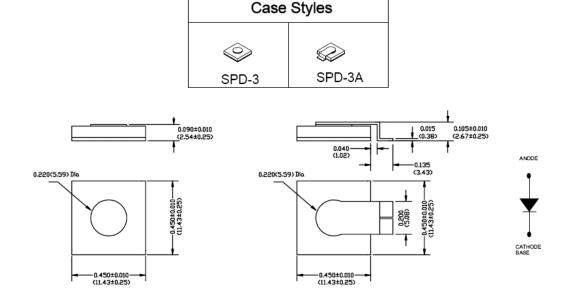
#### **Applications:**

- · Switching power supply
- Converters
- · Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

#### Features:

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- Low reverse leakage current
- High surge capacities
- High frequency operation
- · Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In Inches / mm



SPD-3A SPD-3A

## Suffix "R" Denotes Reversed Polarity

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121SPC045/A

**Technical Data** Data Sheet N1159, Rev. - Green Products

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	45	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	120	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650	А
Non-Repetitive Avalanche Energy(per leg)	E <sub>AS</sub>	$T_J$ =25 $^{\circ}$ C, $I_{AS}$ =11A, L=1.2mH	76	mJ
Repetitive Avalanche Current(per leg)	I <sub>AR</sub>	$I_{AS}$ decaying linearly to 0 in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =1.5 $\times V_R$	11	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	$V_{F1}$	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.66	V
	$V_{F2}$	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.59	V
Max. Reverse Current (per	I <sub>R1</sub>	$@V_R = \text{rated } V_R \text{,Pulse,}$	2.4	mA
leg) *		T <sub>J</sub> = 25 °C		
	$I_{R2}$	$@V_R = rated V_R$ , Pulse,	90	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	CJ	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	4800	pF
(per leg)		$f_{SIG} = 1MHz$ , $V_{SIG} = 50mV(p-p)$		

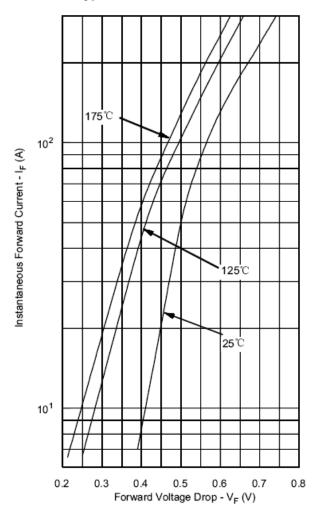
<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

## **Thermal-Mechanical Specifications:**

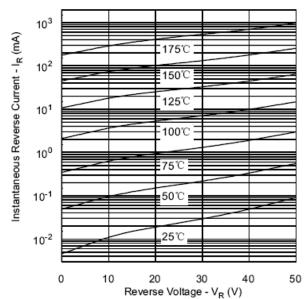
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.20	°C/W
Case Style		SPD-3/A		

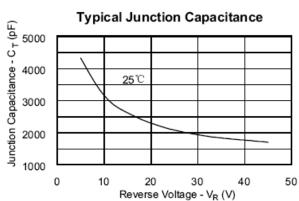
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## **Typical Forward Characteristics**



## Typical Reverse Characteristics





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Data Sheet N1159. Rev. -

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